BC817-16FSW - BC817-40FSW

45V NPN SMALL SIGNAL TRANSISTOR IN DFN1412-3/SWP

Features

- BV_{CEO} > 45V
- I_C = 500mA High Continuous Collector Current
- Low-Profile 0.6mm-High Package for Thin Applications
- Sidewall Tin Plating for Wettable Flanks in AOI
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **These parts are qualified to JEDEC standards (as references in AEC-Q) for High Reliability. https://www.diodes.com/quality/product-definitions/**
- **An automotive-compliant part is available under separate datasheet (BC817-16FSWQ-BC817-40FSWQ).**

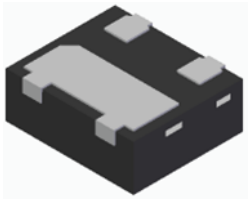
Mechanical Data

- Package: U-DFN1412-3/SWP (Type A)
- Package Material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.0050 grams (Approximate)

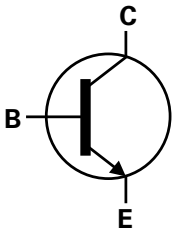
Application

- Switching and amplification

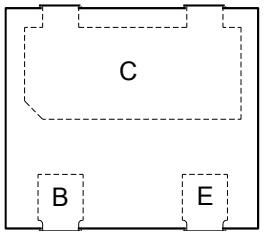
U-DFN1412-3/SWP (Type A)



Bottom View



Device Symbol



Top View
Pin-Out

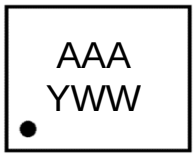
Ordering Information (Note 4)

Orderable Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
BC817-16FSW-7	U-DFN1412-3/SWP (Type A)	2W4	7	8	5,000	Reel
BC817-25FSW-7	U-DFN1412-3/SWP (Type A)	2W5	7	8	5,000	Reel
BC817-40FSW-7	U-DFN1412-3/SWP (Type A)	2W6	7	8	5,000	Reel

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

U-DFN1412-3/SWP (Type A)



AAA = Product type Marking Code
YWW = Date Code Marking
Y = Last Digit of Year (ex: 4 = 2024)
WW = Week Code 01 to 53

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	45	V
Emitter-Base Voltage	V_{EBO}	6	V
Continuous Collector Current	I_C	500	mA
Peak Pulse Collector Current	I_{CM}	1	A
Peak Base Current	I_{BM}	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_D	500	mW
	(Note 6)		1.25	W
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	250	°C/W
	(Note 6)		100	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge – Charged Device Model	ESD CDM	1000	V	C3

Notes:
5. For a device mounted with the exposed collector pads on minimum recommended pad layout that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
6. Same as Note (5), except the device is mounted with 1-inch square pad and 2oz. copper.
7. Refer to JEDEC specification JESD22-A114 and JESD22-C101.

Thermal Characteristics and Derating Information

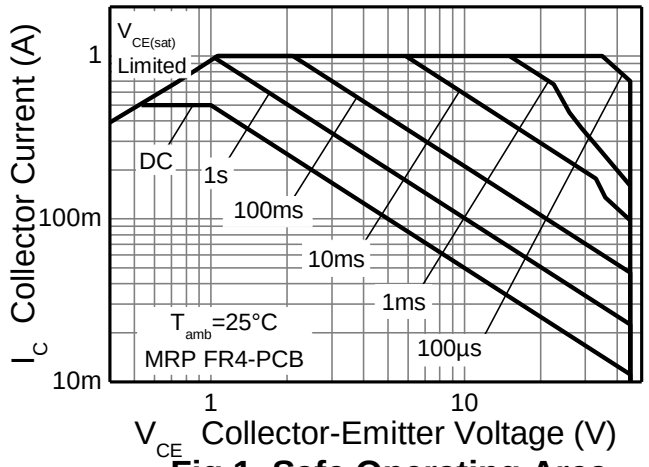


Fig.1 Safe Operating Area

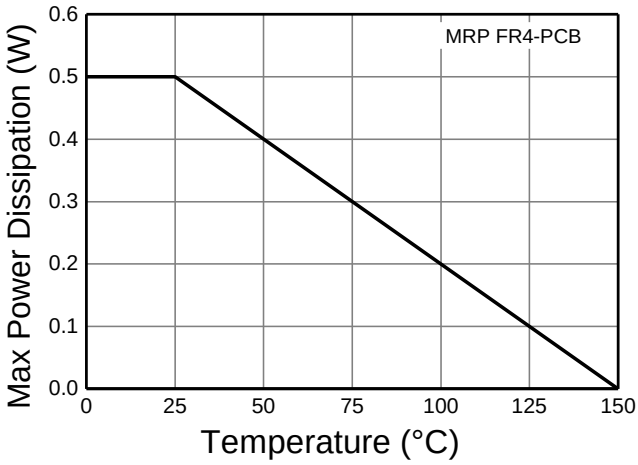


Fig.2 Derating Curve

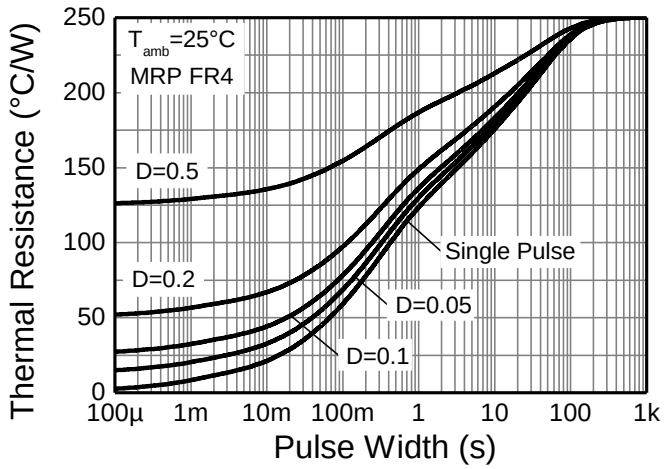


Fig3. Transient Thermal Impedance

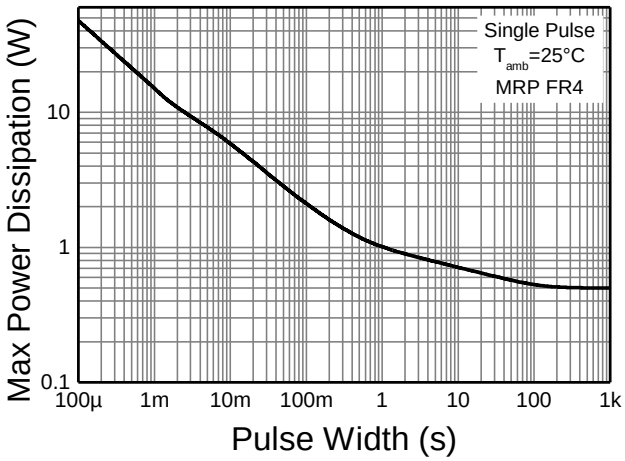


Fig.4 Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Conditions
Collector-Base Breakdown Voltage		BV_{CBO}	50	—	—	V	I_C = 100µA
Collector-Emitter Breakdown Voltage (Note 8)		BV_{CEO}	45	—	—	V	I_C = 10mA
Emitter-Base Breakdown Voltage		BV_{EBO}	7	—	—	V	I_E = 100µA
Collector-Base Cutoff Current		I_{CBO}	—	—	100	nA	V_{CB} = 36V, I_E = 0
			—	—	5	µA	V_{CB} = 36V, I_E = 0, T_A = +150°C
Emitter-Base Cutoff Current		I_{EBO}	—	—	100	nA	V_{EB} = 5.6V, I_C = 0
DC Current Gain (Note 8)	BC817-16FSW	h_{FE}	100	—	250	—	V_{CE} = 1V, I_C = 100mA
	BC817-25FSW		160	—	400		V_{CE} = 1V, I_C = 100mA
	BC817-40FSW		250	—	600		V_{CE} = 1V, I_C = 100mA
	All variants		40	—	—	—	V_{CE} = 1V, I_C = 500mA
Collector-Emitter Saturation Voltage (Note 8)		$V_{CE(sat)}$	—	—	700	mV	I_C = 500mA, I_B = 50mA
Base-Emitter Turn-on Voltage (Note 8)		$V_{BE(on)}$	—	—	1.2	V	V_{CE} = 1V, I_C = 500mA
Transition Frequency		f_T	100	—	—	MHz	V_{CE} = 5V, I_C = 10mA, f = 100MHz
Collector-Base Capacitance		C_{cbo}	—	—	12	pF	V_{CB} = 10V, f = 1MHz

Note: 8. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤2%.

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

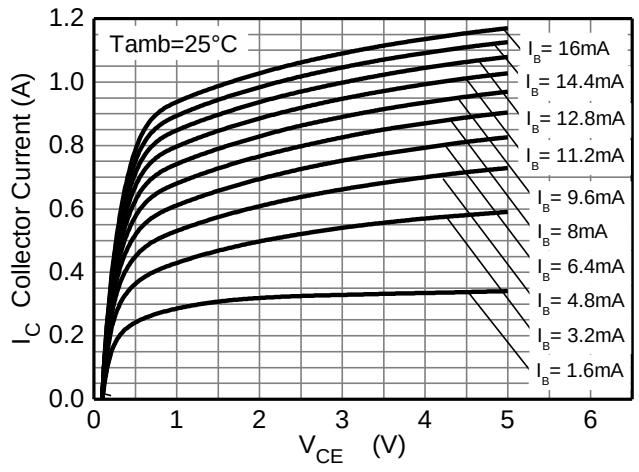


Fig.5 I_C v V_{CE} (BC817-16FSW)

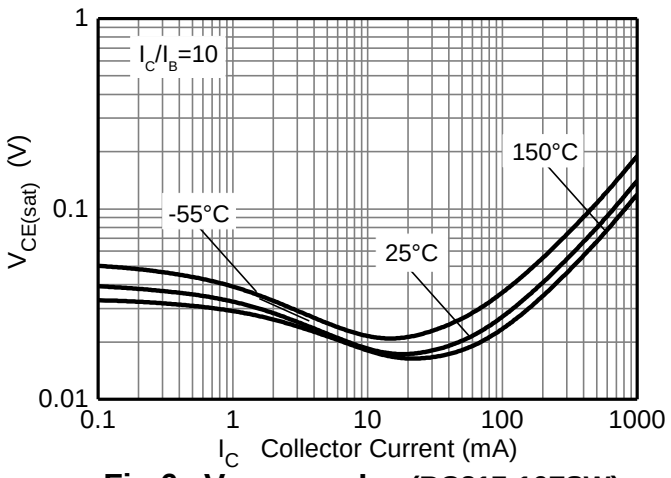


Fig.6 $V_{CE(sat)}$ v I_C (BC817-16FSW)

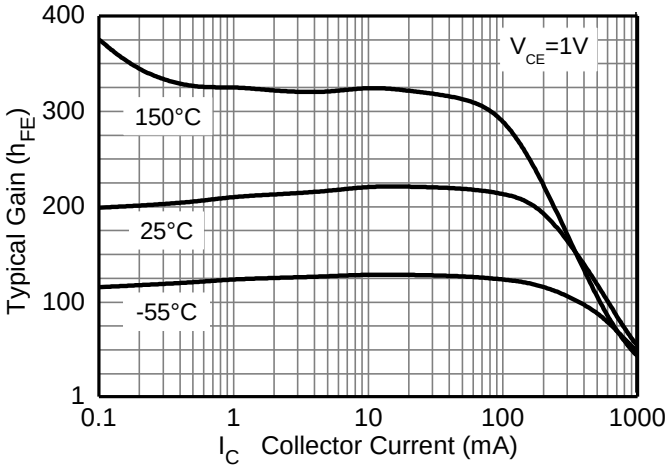


Fig.7 h_{FE} v I_C (BC817-16FSW)

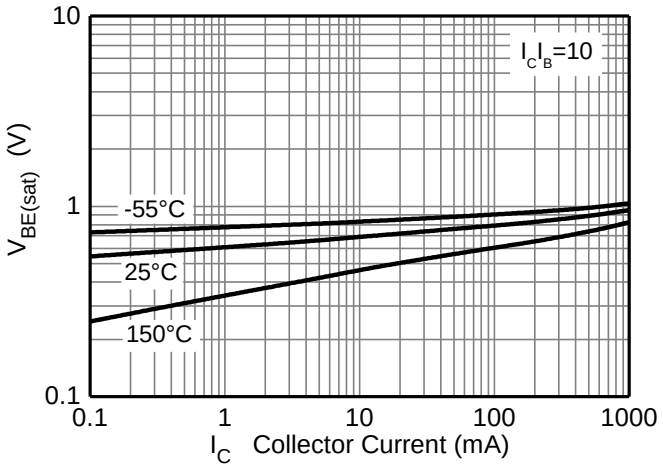


Fig.8 $V_{BE(sat)}$ v I_C (BC817-16FSW)

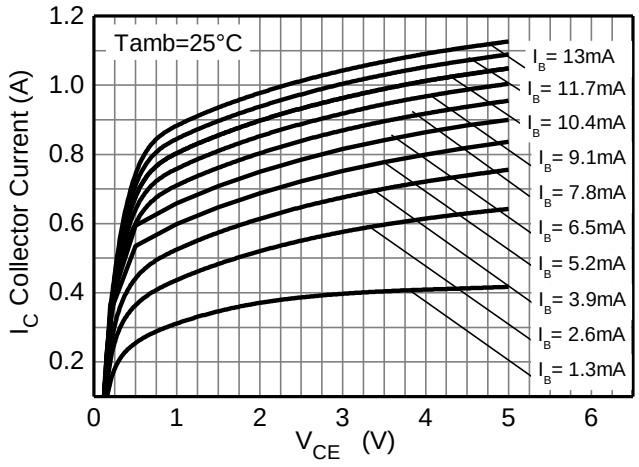


Fig.9 I_C v V_{CE} (BC817-25FSW)

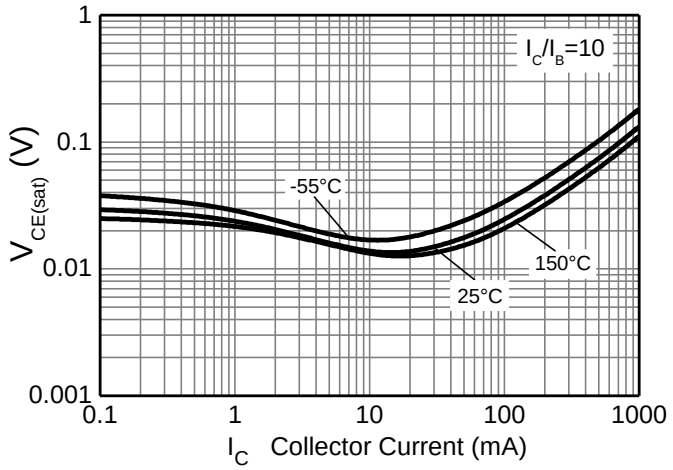


Fig.10 $V_{CE(sat)}$ v I_C (BC817-25FSW)

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

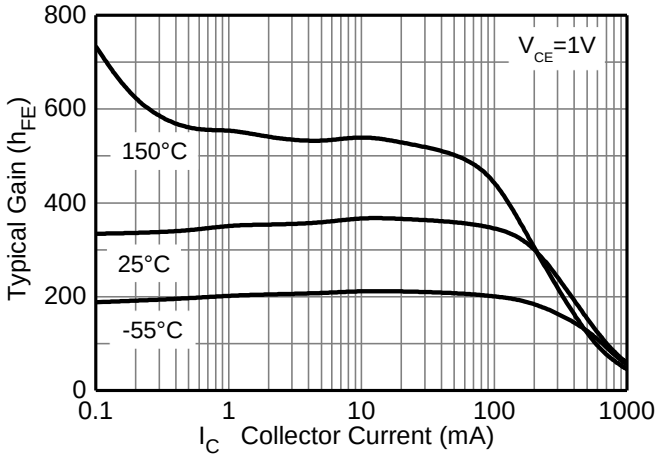


Fig.11 h_{FE} v I_C (BC817-25FSW)

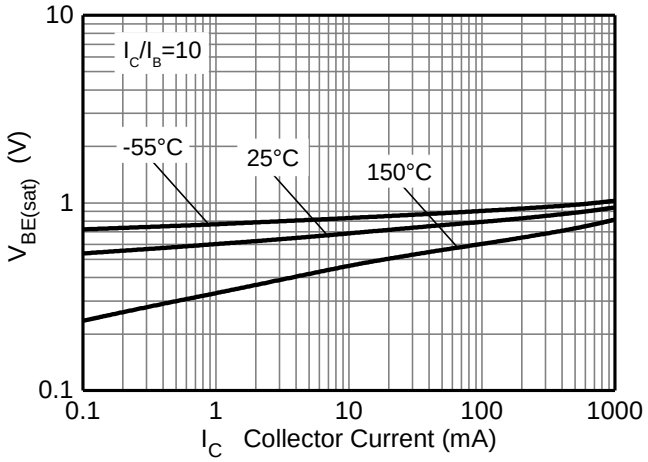


Fig.12 $V_{BE(sat)}$ v I_C (BC817-25FSW)

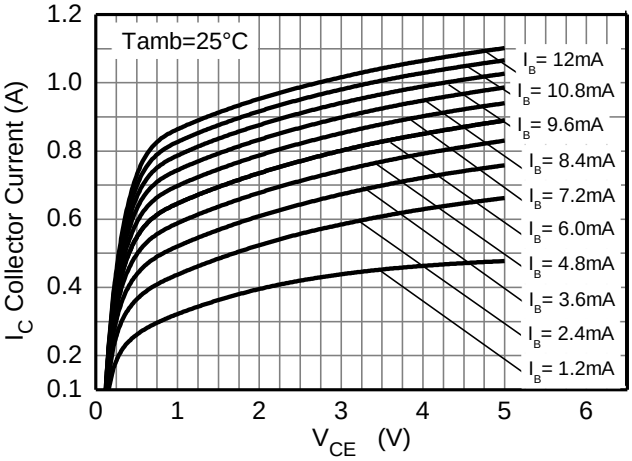


Fig.13 I_C v V_{CE} (BC817-40FSW)

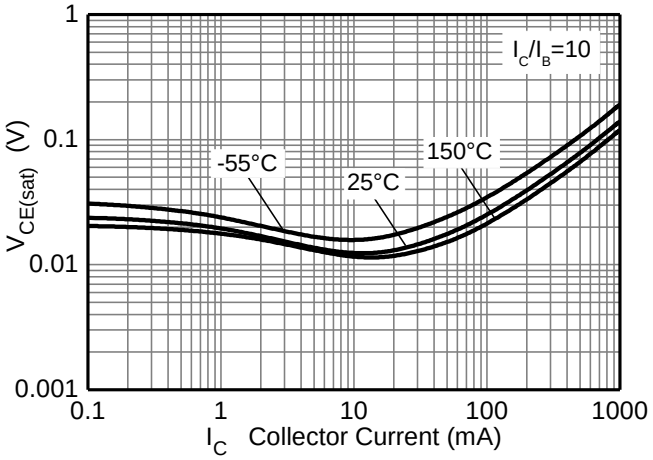


Fig.14 $V_{CE(sat)}$ v I_C (BC817-40FSW)

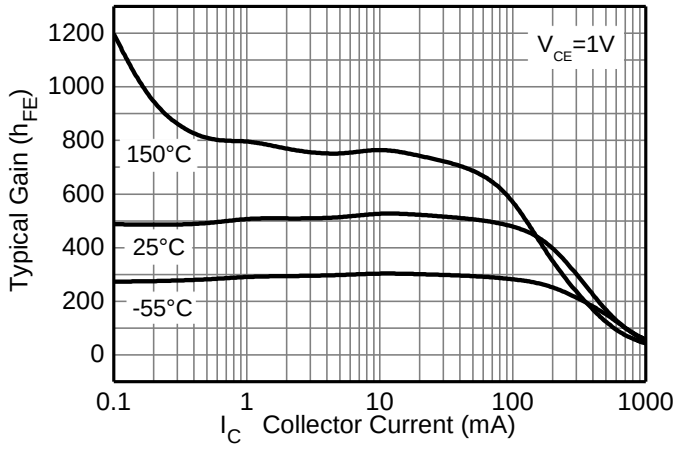


Fig.15 h_{FE} v I_C (BC817-40FSW)

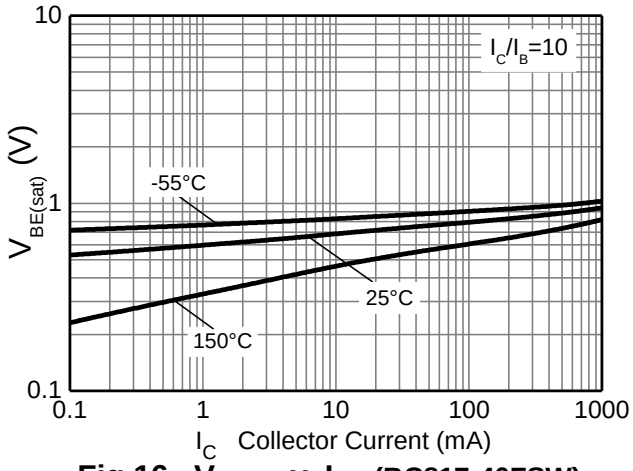
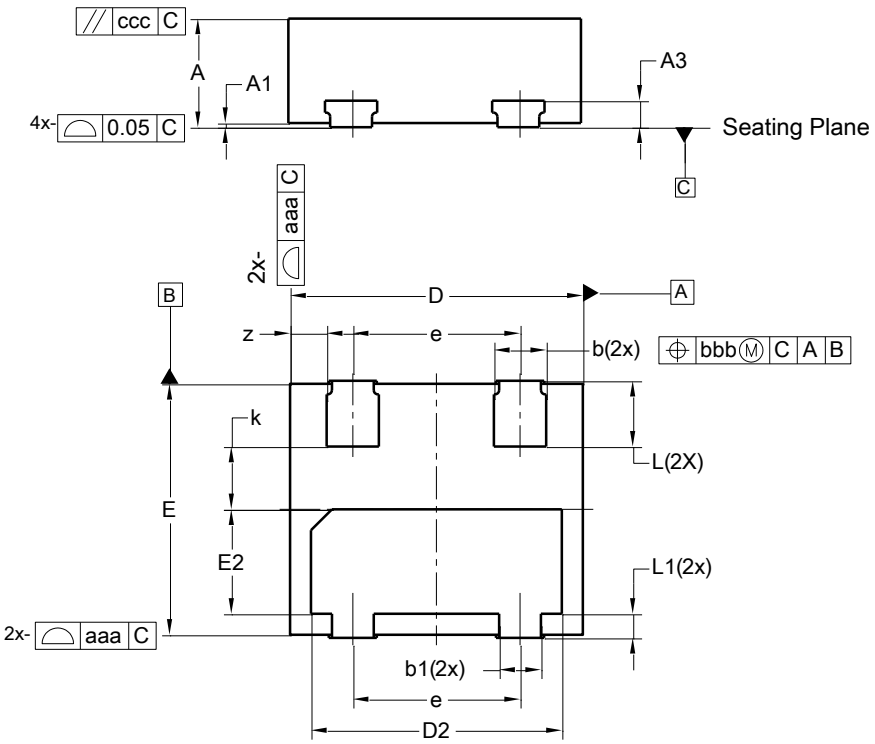


Fig.16 $V_{BE(sat)}$ v I_C (BC817-40FSW)

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN1412-3/SWP (Type A)



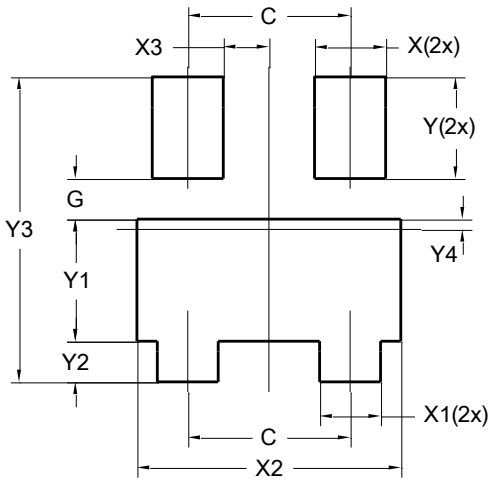
U-DFN1412-3/SWP (Type A)			
Dim	**Min**	**Max**	**Typ**
A	0.47	0.57	0.52
A1	0.00	0.05	0.03
A3	–	–	0.127
b	0.20	0.30	0.25
b1	0.15	0.25	0.20
D	1.35	1.45	1.40
D2	1.10	1.30	1.20
e	0.80 BSC		
E	1.15	1.25	1.20
E2	0.40	0.60	0.50
k	–	–	0.30
L	0.265	0.365	0.315
L1	0.065	0.165	0.115
z	–	–	0.175
aaa	0.25		
bbb	0.10		
ccc	0.10		
All Dimensions in mm			

Note: 9. Side wall tin plated package for wettable flanks in AOI.

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN1412-3/SWP (Type A)



Dimensions	Value (in mm)
C	0.800
G	0.200
X	0.350
X1	0.300
X2	1.300
X3	0.225
Y	0.500
Y1	0.600
Y2	0.200
Y3	1.500

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